

**SYNTHESIS, CHARACTERIZATION, ELECTRICAL CONDUCTIVITY
AND CATALYTIC ACTIVITY OF NANOSIZED GAMMA
IRRADIATED AND UNIRRADIATED $ZnMn_2O_4$ SPINEL**

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(Received: 14/9/2011)

ABSTRACT

Nano zinc manganite ($ZnMn_2O_4$) samples have been prepared using hydrothermal method in presence and absence of surfactants. The samples were characterized by XRD, FT-IR, and electron microscopy (SEM) as well as (TEM). Catalytic activity for investigated samples as well as, dc- and ac- electrical conductivity were studied. The effect of Gamma radiation on the studied properties are investigated. All samples showed tetragonal spinel structure with an average crystallites sizes lay in the range 18 – 85 nm. The samples showed semiconducting behavior in which the electrical conduction occurred via electron exchange amongst manganese ions situated on octahedral sites in the spinel structure. The particle size, morphology, electrical and catalytic activity were affected by each of preparation conditions and γ - irradiation process. The irradiation causes a change in each of the catalytic activity and the conductivity values of the investigated material. Hopping mechanism between Mn^{3+} and Mn^{4+} in $Zn^{2+}_{1-x} [Zn^{2+}_x Mn_{2-x}^{3+} Mn^{4+}_x] O_4^{2-}$ samples is used to explain the conducting behavior. The catalytic activity of investigated samples increases by gamma irradiation process due to the change occurring in the oxidation states of manganese ions.

Keywords: Nanomaterials, zinc manganate, γ -irradiation, electrical conductivity and catalytic activity

INTRODUCTION

Nanometer-scale materials with the size of 1–100 nm have attracted considerable attention in recent years due to their interesting properties arising from quantum size effect. In nanophase materials, a majority of atoms, molecules, or ions reside in the grain boundaries or within one or two layers from the boundary [F. Liu et al. (2004), F. Liu et al. (2006), F. Liu et al. (2007) and S.V Bobylev et al. (2004)]. These grain boundaries contain a high density of defects like vacancies, dangling bonds, which can play an important role in the transport properties of these materials. Several synthetic methods and approaches have been applied for preparing nanomaterial with different shapes [J. M. Kim et al. (2006), E. Hosseini et al. (2009), Y. Jun et al. (2005)]. General approaches for shape control and production of anisotropic nanostructures rely on the availability of surfactants, which preferentially absorbed on specific crystallographic faces. With ever increasing energy costs, the hydrothermal method could be possibly very attractive for fine powder preparation because of the low temperature involved, crystal size and the morphology of the powders may be by reaction conditions and the good sinter ability of the formed powders [K. Hanzhong et al. (2007), B. Ding et al. (2009), J. Zhang et al. (2010)].

ZnMn₂O₄ is one of the promising materials which can be used as negative temperature coefficient (NTC) thermistors [S. Guillemet-Fritsch et al. (2000)], as catalytic material [G. Ferraris et al. (2002)] and as cathodic material of the secondary batteries [F. Liu et al. (2004)] due to their excellent electrochemical properties. It is expected that all of these properties to be dependent on the particle size and their morphology. Therefore, this work was designed to prepare nano ZnMn₂O₄ by hydrothermal method in absence and presence of different surfactants. The materials obtained were characterized by X-ray diffraction (XRD), Fourier transform infrared (FTIR), scanning electron microscopy (SEM) and transmission electron microscopy (TEM). The effect of grain size and γ - irradiation on each of the electrical properties and catalytic activity of the prepared samples have been studied.

EXPERIMENTAL

Materials

All the chemical reagents used in the experiment were reagent grade and used without further purification and treatment. The surfactants used in the preparation method were divided into three different groups: (a) Cationic surfactants: cetylpyridinium bromide monohydrate (CPB) {CH₃(CH₂)₁₅NC₅H₅Br.H₂O} (98%) provided from Aldrich; (b) Anionic surfactants: dodecylbenzene sulphonic acid (Sulph) {CH₃(CH₂)₁₁C₆H₄SO₃H} provided from chemicals and dyes company, Kafr El Doar and (c) Nonionic surfactants: triton X-100 (TX) {C₁₄H₂₂O(C₂H₄O)_n} provided from Arsamco.

Sample preparation

A mixed solution of 1 ml H₂O₂ (3%), 3 ml of 5×10⁻³ M surfactant and 6 ml NaOH (0.6 M) was poured slowly into a Teflon-lined stainless-steel autoclave filled with 3 ml Mn(NO₃)₂ (0.3 M) while stirring vigorously, and the reaction solution was continually stirred and kept for 20 min at room temperature. 100 ml of Zn(NO₃)₂·6H₂O (0.15 M) (Carlo Erba RPE reagent grades) was added into the reaction solution and then hydrothermally heated in the Teflon-lined stainless-steel autoclave at 500 K for four days. After that the samples were cooled to room temperature. The formed precipitates were filtered and washed with distilled water several times until pH=7, and finally dried in an oven for about 24 h at 363 K. Half of the prepared samples were irradiated at 100 KGy using Co⁶⁰.

The prepared samples are denoted as S, S_{CPB}, S_{TX}, and S_{sulph} for the samples prepared without surfactant and by using CPB, triton-x-100, and sulphonic surfactant, respectively. The irradiated sample is denoted by *.

Techniques

X-ray diffraction was performed on the investigated samples using a Philips X'Pert Pro Super diffractometer with CuK α radiation ($\lambda = 1.54 \text{ \AA}$) in the range of $2\theta = 10-80^\circ$. The density was determined by both the immersion Archimedes method and X-ray diffraction. The infrared spectra of the samples were recorded using a Bruker-FTIR. The absorbance was automatically registered against wavenumber (cm⁻¹). Scanning electron microscopy (SEM) and transmission electron micrograph (TEM) analyses were done by using JEOL-JEM-6360 unit and Philips CM-12 unit, respectively. The catalytic decomposition of H₂O₂ was used as a model reaction for determining the catalytic activity of the gamma irradiated and unirradiated samples at temperatures between 303 and 313 K. The reaction was followed up through a gasometrical measurement of evolved oxygen [N. A. Youssef et. al. (1993)].

For electrical measurements, the powder samples were pressed uniaxially into a pellet of thickness 1–2 mm and of diameter 7 mm by applying pressure of ~ 0.3 Gpa for 3 min. Both faces of the pellets were coated with fine quality silver paint for good electrical contacts. DC conductivity was measured in the temperature range 300–400 K by the four terminal technique. The temperature was limited to 400 K to prevent grain growth and to ensure that the main particle size remained the same in the entire temperature range. AC conductivity was measured by the two-probe method using

Fluke PM 6306 programmable automatic (RCL) bridge at frequencies from $10^2 - 10^6$ Hz in the same temperature range as for dc- conductivity.

RESULTS AND DISCUSSION

X-ray diffraction analysis

X-ray diffraction patterns of the investigated manganite samples are presented in Fig. (1). For all samples, the same patterns were observed with well developed (hkl) reflections, which can be well indexed on the basis of the tetragonal spinel structure with the space group of $I4_1/amd$ JCPDS file (71-2499) [S. Guillemet-Fritsch et. al. (2000)]. No trace of impurity phases of starting materials is observed in the present patterns, indicating the high purity of the sample.

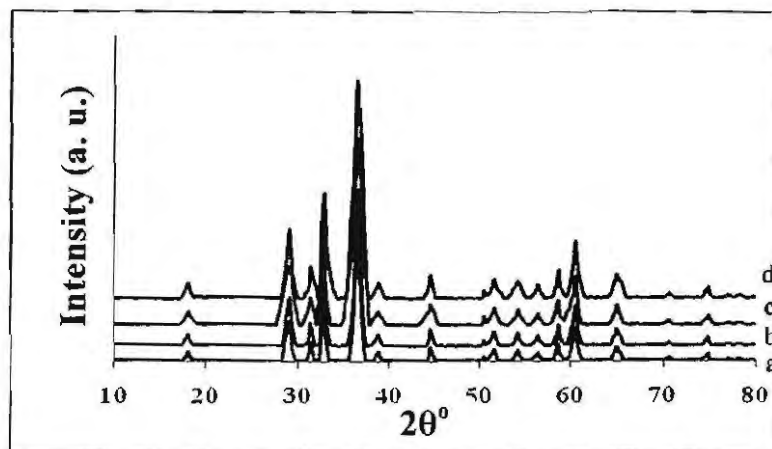


Fig. 1: X-ray diffraction patterns of : a- S_{sulph} b- S c- S_{TX} and d- S_{CPB}

The crystallites sizes D_s , for the investigated samples were determined by using the Scherrer's equation [H. P. Klug, (1970)]:

$$D_{XRD} = 0.9 \lambda / \beta \cos \theta \quad (1)$$

where λ is the X-ray wave length, θ the Bragg's angle and β is the pure full width of the diffraction line at half of the maximum intensity. The results showed D_{XRD} in the range of 18 - 85 nm with an error of 20%, Table (1). The irradiated samples showed larger particle size than that of unirradiated ones. This may be due to creation of some lattice defects as a result of ionizing radiation.

The X-ray density was calculated using the formula: $D_{XRD} = ZM/NV$ (2)

where Z is the number of molecules per unit cell ($Z = 4$); M is the molecular weight; N is the Avogadro's constant and V is the volume of unit cell.

The bulk density (d_A) was also measured by the Archimedes principle. The percentage porosity (P) of the samples was then calculated using the relation [M. Kosaki et. al. (1979)]:

$$P = (1 - d_A/d_{XRD}) \times 100 \quad (3)$$

Each of the bulk density and porosity values are given in **Table (1)**, which shows an increase in the porosity with decreasing the particle size of the grains.

Table (1) : Lattice parameters, density and porosity of investigated ZnMn₂O₄ samples

Sample	Lattice constant (nm)	Volume of Unit Cell $\times 10^{22} \text{ m}^3$	d_{XRD} g/cm ³	d_{A} g/cm ³	D_{TEM} (nm)	D_{XRD} (nm)	P%
S _{sulph}	a=0.571, c=0.922	3.006	5.285	4.067	22	20	23.0
S _{sulph}	a=0.572, c=0.923	3.020	5.261	4.024	19	18	23.5
S [*]	a=0.572, c=0.922	3.016	5.268	4.086	42	38	22.4
S	a=0.573, c=0.923	3.030	5.243	4.059	34	32	22.6
S _{TX}	a=0.573, c=0.923	3.030	5.243	4.096	75	72	21.8
S _{TX}	a=0.573, c=0.924	3.033	5.238	4.059	66	63	22.5
S _{CPB}	a=0.573, c=0.923	3.030	5.243	4.416	90(diam)	85	15.7
S _{CPB}	a=0.573, c=0.924	3.033	5.238	4.373	82(diam)	81	16.5

SEM and TEM analysis

Figs. (2 (a) and (b)) show the SEM and TEM of some γ -irradiated and unirradiated powdered samples, respectively. The images analysis reveals the role of surfactants as a capping agents. The morphology of the samples prepared in absence of surfactant showed a range of shapes including finely dispersed spherical particles with high homogeneity and cotton like structure. And the morphology of the samples prepared using each of the anionic (sulphonic) and nonionic surfactant (triton) showed nanoparticles with different shapes. Whereas, the samples prepared using CPB surfactant showed the formation of dispersed nanorod particles. Cationic surfactant such as CPB has been successfully used as the morphology-directing agent for the synthesis of one-dimensional nanostructures, such as CuO, PbO₂, Pb₃O₄ and Co₃O₄ nanorods [S. Lian et. al. (2007)]. In their synthesis, due to electrostatic interactions, inorganic precursor and cationic surfactant CPB can form different conformational inorganic-surfactant composite templates or used as a capping agent.

The image analysis for some irradiated samples showed surface morphologies and voids between the particles grains differ to some extent than that of unirradiated ones. Moreover, the pores sizes became larger after irradiation process. This indicates that the high ionization radiation produced an effect on the surfaces of the samples. This may be attributed to the creation of some lattice defects by the ionizing radiation.

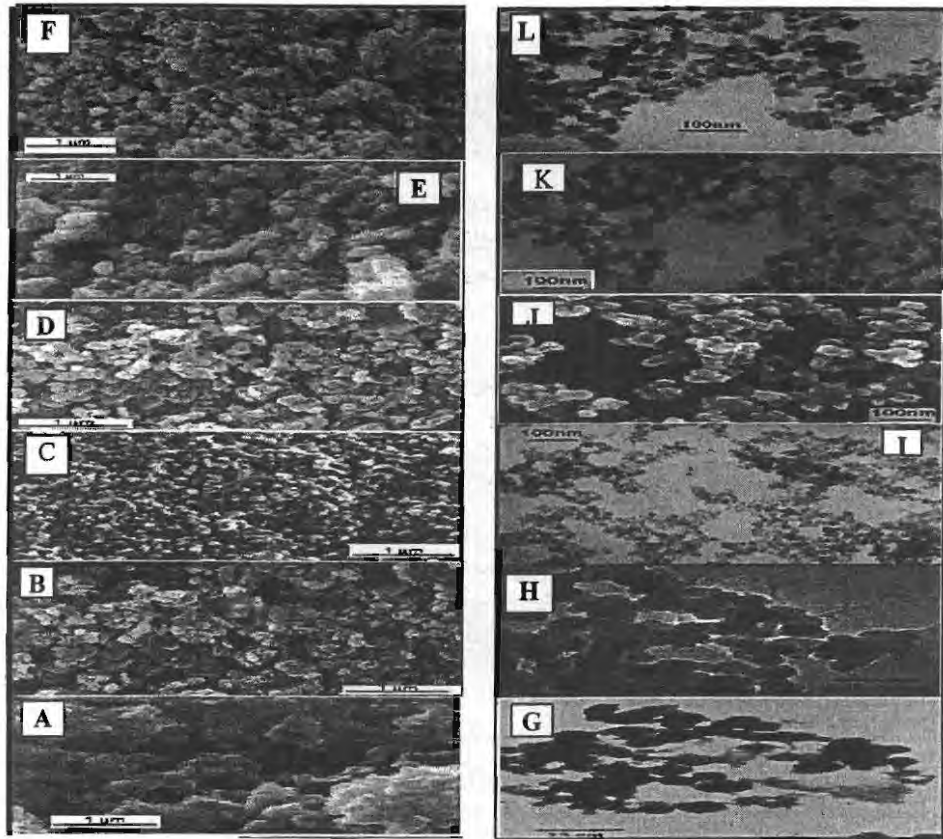


Fig. 2a: SEM of: A- S B- S_{sulph} C- S_{TX} D- S_{CPB} E- S^* and F- S^*_{TX} Fig. 2b: TEM of: G- S_{sulph} H- S I- S_{TX} J- S_{CPB} K- S_{CPB}^* and L- S^*

Generally, the different morphologies and sizes of crystallites formed during the hydrothermal crystallization in presence of surfactants can be explained on the basis of the balance between nucleation and growth rates. With increase in each of the supersaturation and adsorption of surfactant on the crystal faces, both growth and nucleation rates increase. Consequently, when the growth rate dominates over the nucleation rate, crystallite sizes increase, while in the case of nucleation rate domination, crystallite size decreases [L. Carbone et. al. (2010)].

The mean grain sizes D_{TEM} of investigated samples are slightly larger than D_{XRD} and lie between 19 - 90 nm, Table (1). This may be attributed to either the presence of non-crystalline materials at the lattice surface or to the different approach of two techniques. In XRD, we determine the mean particle diameters and the shape factor used is not definite determined (value used in our calculations is 0.9) any change in the shape factor will cause a change in the calculated size.

FT-IR spectroscopy

Infrared spectroscopy for the γ -irradiated and non-irradiated samples showed vibrations bands in the range 400 to 1000 cm⁻¹[X. Duan et. al. (2011)], which is usually assigned to the vibration of ions in the crystal lattice. The main bands appeared are listed in Table (2). The main features found in the spectra are:

(i) All samples showed vibration bands of the manganese ions on both the tetrahedral (ν_1) and octahedral (ν_2) sites. (ii) The positions of the bands are slightly dependent on the type of surfactant used. But some broadens in the peaks are observed with decreasing the particle size. The other strong peak broadens and even cleaves. This may

Table (2) : FTIR data of investigated samples

[] irradiated samples be due to the existence of more imperfections in nanometer particles, leading to the wide distribution of vibration frequency of the chemical bond and the dramatically decreased symmetry.

(iii) The band positions of irradiated samples are slightly shifted to higher and lower wavelengths than that of unirradiated ones. This may be attributed to the change producing in the valence state of the metal ions after irradiation process.

Vibration Band (cm ⁻¹)	S	S _{TX}	S _{CPB}	S _{sulph}	Structural group and Chemical bonds
ν_1	616	616	624	622	Due to Mn ⁴⁺ -O ²⁻ bond vibration of tetrahedral group [E. Hosseini et. al. 2009].
	[617]	[617]	[621]	[619]	
ν_2	500	500	487	501	Due to stretching vibrations of octahedral group.[E. Hosseini et. al. 2009].
	[498]	[498]	[495]	[505]	
ν_3	855	867	855	778	Due to vibration of divalent tetrahedral cations [J. M. Kim et. al. 2006].
	[850]	[869]	[850]	[772]	
ν_4	442	445	441	449	Due to Mn ²⁺ -O ²⁻ bond vibration in octahedral sites[E. Hosseini et. al. 2009].
	[438]	[440]	[440]	[442]	

DC-Conductivity

The temperature dependence of dc-conductivity σ_{dc} for γ -irradiated and unirradiated samples has been studied. All the samples showed a thermally activated process. Typical plot is shown in Fig. (3).

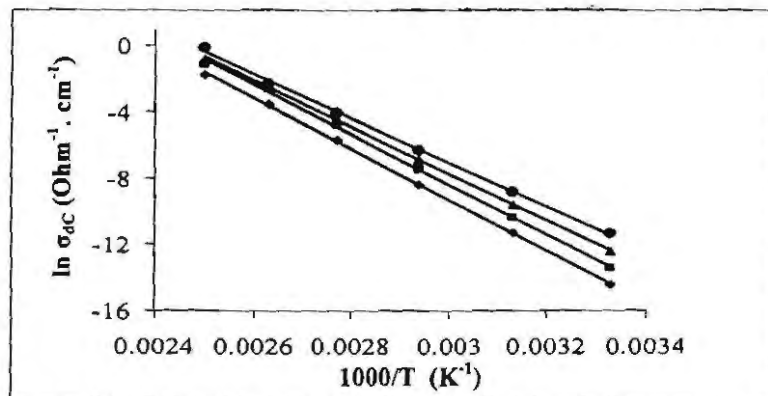


Fig. 3: The temperature dependence of DC-conductivity for: (●); S_{CPB} , (▲); S_{TX} , (■); S , and (◆); $S_{(Sulph)}$

This can be explained according to the relation:

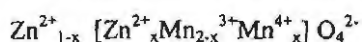
$$\sigma_{dc} = \sigma_0 \exp(-E_{dc}/kT) \quad (4)$$

where σ_0 is the pre-exponential factor, E_{dc} the activation energy k the Boltzmann constant. E_{dc} was calculated from the slope of $\ln \sigma_{dc}$ against T^{-1} using least squares method. The conductivity data are summarized and given in Table (3). It may be noted that, σ_{dc} is conspicuously size dependent; it increases as the particle size increases

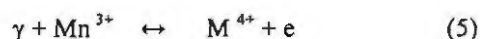
$$S_{CPB} > S_{TX} > S > S_{Sulph}$$

This is due to either the fact that samples with small grain consist more number of grain boundaries than grains. The grain boundaries are the regions of mismatch between the energy states of adjacent grains and hence act as barriers to the flow of electrons or the increase of the mobility of charge carriers (electrons) by their attraction in case of the solids prepared by using cationic surfactant and decrease this mobility by repulsion between charge carriers and the solid prepared by anionic surfactant.

It is well known that the electrical conduction in oxides containing transition metal ions in different oxidation states takes place by means of hopping electrons between these different oxidation states [N. Ma et. al. (2003), M.G. El-Shaarawy (2000), R.V. Wandekar et. al. (2009)]. Thus, it is expected that the conduction mechanism in our samples with spinel structure is attributed to the hopping of electrons between the manganese ions with different valence states at octahedral sites [T. Battault et. al. (1995)]. This is due to their smaller separating distance than that present in tetrahedral sites. This hopping conductivity is possible only if some Zn^{2+} cations are located on the octahedral sites of the spinel structure. Then an equivalent proportion of Mn^{4+} is created on the same sites, in order to maintain the electrical neutrality as it is described in the following formula [S. uillemet- Fritsch et. al. (2000)]:



The conductivity results of γ -irradiated samples showed an increase in the electrical conductivity values comparable with that found for unirradiated ones, whereas the activation energy (E_{dc}) is not changed. This non-change in E_{dc} values means that the electrical conduction mechanism is the same in all irradiated and unirradiated samples. But the increase in conductivity values by irradiation refers to a change in the rate of hopping process due to a change occurring in the ratio of Mn valence states present in octahedral sites. Thus, the γ -irradiation effect on the electrical conductivity may be explained according to the following interaction



This reversible interaction leads to increase the amount of Mn^{4+} ions that causing an increase in the redox ratio $\text{Mn}^{4+}/\text{Mn}^{3+}$ present in the octahedral sites. This causes an increase in the hopping process and hence an increase in electrical conductivity values.

Table (3): Conductivity data of γ -irradiated and unirradiated ZnMn₂O₄ samples at 300 K.

Sample	Particle Size (nm)	σ (ohm ⁻¹ .cm ⁻¹)	E_{dc} (eV)
S_{sulph}^*	22	$[9.2 \times 10^{-7}]$	[1.25]
S_{sulph}	19	5.3×10^{-7}	1.31
S^*	42	$[3.82 \times 10^{-6}]$	[1.17]
S	34	1.41×10^{-6}	1.26
S_{TX}^*	75	$[9.82 \times 10^{-6}]$	[1.11]
S_{TX}	66	3.99×10^{-6}	1.19
S_{CPB}^*	90	$[4.32 \times 10^{-5}]$	[1.04]
S_{CPB}	82	1.12×10^{-5}	1.16

[] irradiated data

AC-conductivity

In order to give information on the type of polarization present in the samples, the ac-electrical conductivity (σ_{ac}), at temperatures between 300-400 K and at frequency range of $10^2 - 10^6$ Hz were studied for irradiated and unirradiated samples. Fig. (4) shows the frequency dependence of σ_{ac} at 373 K. The same variation is observed for all samples with different particle sizes.

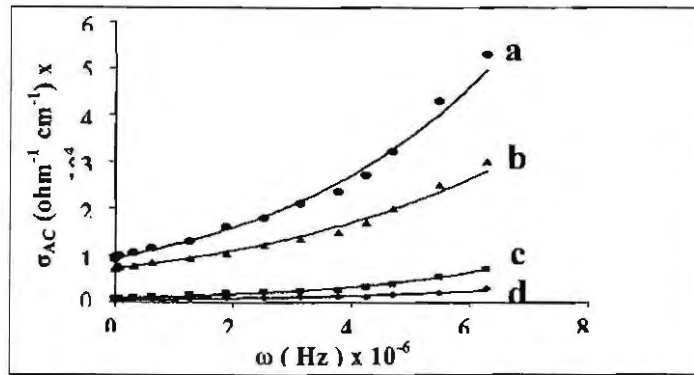


Fig. 4: The frequency dependence of AC-conductivity for: (a); S_{CPB} , (b); S_{TX} , (c); S , and (d); S_{Suloh}

All the samples show an increasing trend in the ac - conductivity as the frequency increases, especially at higher frequencies. The origin of frequency dependence of conductivity in the relaxation phenomenon arises due to mobile charge carriers. However, in a hopping model, it is possible to distinguish different characteristic regions of frequency at low frequencies where the conductivity is almost constant; the mechanism of transport of charge takes place via many paths. The hopping mechanism becomes the sole contribution to the conductivity process in the frequency regions where the conductivity is strongly dependent on frequencies. The relation between ac - electrical conductivity, real dielectric constant ϵ' , angular frequency, and dielectric loss ϵ'' can be expressed as [B. Kumar et. al. (1994)]:

$$\sigma_{ac} = \epsilon' \epsilon_0 \omega \tan \delta \quad (6)$$

This equation is derived considering the double layer model in which the inhomogeneous natures of two different layers are involved [C. Koops et. al. (1951)]. According to this model, the dielectric spinel material consists of two layers. The first layer consists of large grains of fairly conducting material, which is separated by the second layer, which is a thin layer of grain boundaries of relatively poor conducting material [M. A. Eihiti et. al. (1996)]. The grain boundaries of nanomaterials have a vital role to play in their transport properties since a greater number of atoms are present in the grain boundary or within a few atomic layers from the boundary [R.W. Siegel et. al. (1994), C. S. Narayana et. al. (1994), S. Kurien et. al. (2006)]. Electrical conductivity in nano zinc manganite is due to the electron hopping, which involves exchange of electrons between Mn^{3+} and Mn^{4+} ions in the octahedral sites. According to Eq. (6) the ac -electrical conductivity increases with frequency in nano $ZnMn_2O_4$. The contributions from grain boundaries on σ_{ac} are effective at lower frequencies, while grains of the inner layer play a major role in conduction mechanism at higher frequencies.

Catalytic activity

The catalytic activity of γ -irradiated and unirradiated ZnMn₂O₄ was tested in the decomposition of hydrogen peroxide in aqueous solution at temperatures between 303 and 323 K. The decomposition kinetics of hydrogen peroxide in the presence of the samples was found to follow first order mechanism with respect to H₂O₂. Thus, plots of $\ln(a/a-x)$ versus t were linear over about 80% of the total reaction time. Typical plots are given in Fig. (5). The rate constant (k , min⁻¹) of the catalyzed reactions was calculated and listed in Table (4). The unirradiated samples were found to have catalytic activity less than those of irradiated ones. This effect of irradiation process on the catalytic activity can be understood on the basis of the change occurring in the valence states of the Mn-ions due to irradiation process, as mentioned above. Thus, the catalytic activity in our samples may be attributed to the presence of Mn⁴⁺/Mn³⁺ and Mn³⁺/Zn²⁺ ion pairs, which were also suggested by Selim et al. [M. M. Selim et al. (2010)].

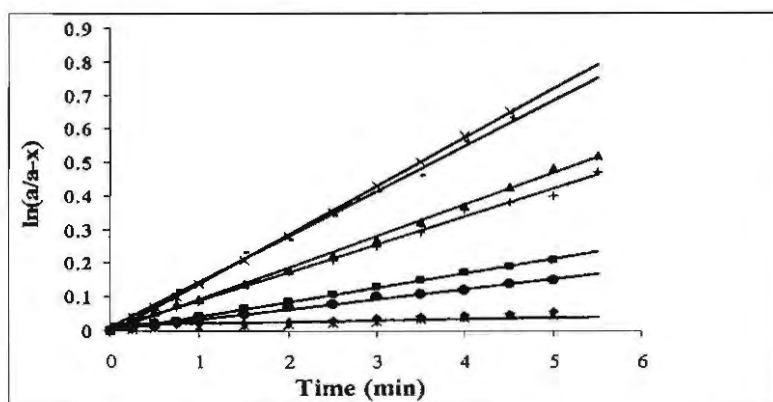


Fig. (5): First order relation $\ln(a/a-x) = kt$ at 303 K: (x); S_{sulph}^{*}, (-); S_{sulph}, (▲); S^{*}, (+); S, (■); S_{TX}^{*}, (●); S_{TX}, (◆); S_{CPB}^{*} and (□); S_{CPB}

It was expected that the catalytic activity increases with decreasing the particle size, i.e. with increasing the surface area. But the results obtained, Table (4), showed a reverse behavior. This refers to that the change in the oxidation states of the active contents in the catalytic samples play the more predominant role in the catalytic process.

Table (4): Reaction rate constant (k) at 303K for H₂O₂ decomposition over irradiated and unirradiated samples.

Sample	Particle Size (nm)	k (min ⁻¹)	lnA	E _a (kJ/mole)
S _{sulph} [*]	22	[0.011]	[18.3]	[49.6]
S _{sulph}	19	0.008	18.9	52.7
S [*]	42	[0.043]	[17.7]	[48.2]
S	34	0.031	18.2	51.4
S _{TX} [*]	75	[0.093]	[16.7]	[44.3]
S _{TX}	66	0.085	17.6	49.2
S _{CPB} [*]	90	[0.145]	[14.7]	[36.4]
S _{CPB}	82	0.131	15.5	41.2

[] irradiated data

CONCLUSION

Nanocrystalline ZnMn₂O₄ were prepared in the range of 19-90 nm using hydrothermal method in presence and absence of surfactants. XRD showed a tetragonal spinel structure for the γ - irradiated and unirradiated samples. The size of the prepared particles have been confirmed through X-ray diffraction and TEM techniques. SEM and TEM images showed surface and particle morphology depends on the surfactant used and irradiation process. The pores sizes on the samples surfaces became larger after irradiation. Both ac and dc conductivity follows Arrhenius-type thermally activated conduction over temperature range investigated and referring to a semiconducting behavior for the γ - irradiated and unirradiated nano ZnMn₂O₄ samples. The irradiation causes a change in each of the catalytic activity and the conductivity values of the investigated material. Hopping mechanism between Mn³⁺ and Mn⁴⁺ in Zn^{2+_{1-x}} [Zn^{2+_x}Mn^{3+_{2-x}}Mn^{4+_x}] O₄²⁻ samples is used to explain the conducting behavior. The catalytic activity of investigated samples increases by gamma irradiation process due to the change occurring in the oxidation states of manganese ions.

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المخلص العربي

تحضير، توصيف، النشاط الحفزي و التوصيل الكهربى لمنجنيت الزنك ذات الحجم النانوى المشععة بأشعة جاما وغير المشععة

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تم تحضير عينات منجنيت الزنك في حجم النانو، وذلك بواسطة الطريقة الهيدروحرارية (Hydrothermal) في وجود وغياب مواد ذات نشاط سطحي. وتم أيضا دراسة تأثير اشعة جاما على بعض الخواص الفيزيائية لها. وجد أن التركيب البلوري للعينات هو الاسينيل وذلك من خلال تحليل حيود الأشعة السينية. وأظهرت صور الميكروسكوب الالكتروني الماسح والنافذ تغيرات كبيرة في شكل الجسيمات وأسطح المواد المحضرة وذلك يرجع لاختلاف نوع المواد ذات النشاط السطحي المستخدمة و يرجع أيضا إلى تأثير عملية التشميع. ووجد أيضا أن حجم المسام ازداد بعد عملية التشميع، وتم حساب حجم الجسيمات ووجد أنها تقع في مدى من 18 إلى ٨٥ نانومتر. وأظهرت نتائج التوصيل الكهربى للعينات المشععة وغير المشععة أنها تسلك سلوك أشباه الموصلات، ووجد إن درجة التوصيل تغيرت نتيجة عملية التشميع، ووجد أن ميكانيكية التوصيل هي عن طريق عملية القفز بين ايونات المنجنيز Mn^{3+} و Mn^{4+} . وأظهرت العينات نشاط حفزي يزداد للعينات المشععة وذلك نتيجة تغير أعداد الأكسدة للمنجنيز.